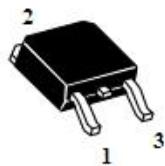
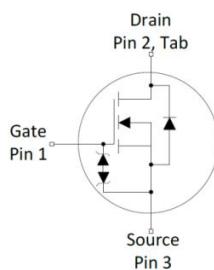


## 7N60(G,D)S

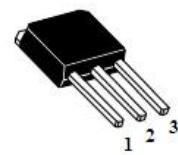
7 Amps, 600 Volts N-Channel Super Junction Power MOSFET

### FEATURE

- 7A, 600V,  $R_{DS(ON)MAX}=0.58\ \Omega$  @  $V_{GS}=10V/3.5A$
- Low gate charge
- Low  $C_{iss}$
- Fast switching
- 100% avalanche tested
- Improved dv/dt capability
- Integrated ESD protection diode



TO-252  
7N60GS



TO-251  
7N60DS

### Absolute Maximum Ratings ( $T_c=25^\circ C$ , unless otherwise noted)

Parameter	Symbol	7N60(G,D)S	UNIT
Drain-Source Voltage	$V_{DSS}$	600	V
Gate-Source Voltage	$V_{GSS}$	$\pm 20$	
Continuous Drain Current	$I_D$	7	A
Pulsed Drain Current (Note 1)	$I_{DM}$	24	
Single Pulse Avalanche Energy (Note 2)	$E_{AS}$	150	mJ
Reverse Diode $dV/dt$ (Note 3)	$dV/dt$	15	V/ns
Operating Junction and Storage Temperature Range	$T_J, T_{STG}$	-55 to +150	°C
Maximum lead temperature for soldering purposes, 1/8" from case for 5 seconds	$T_L$	260	°C

### Thermal Characteristics

Parameter	Symbol	TO-252/251	Units
Maximum Junction-to-Case	$R_{thJC}$	2	°C/W
Maximum Power Dissipation	$T_c=25^\circ C$	63	W

Electrical Characteristics ( $T_c=25^\circ\text{C}$ , unless otherwise noted)						
Parameter	Symbol	Test Conditions	Min	Typ	Max	Units
<b>Off Characteristics</b>						
Drain-Source Breakdown Voltage	$\text{BV}_{\text{DSS}}$	$\text{V}_{\text{GS}}=0\text{V}, \text{I}_D=250\text{uA}$	600	—	—	V
Zero Gate Voltage Drain Current	$\text{I}_{\text{DSS}}$	$\text{V}_{\text{DS}}=600\text{V}, \text{V}_{\text{GS}}=0\text{V}$	—	—	1	$\mu\text{A}$
Gate-source leakage current incl. Zener diode	$\text{I}_{\text{GSSF}}$	$\text{V}_{\text{GS}}=20\text{V}, \text{V}_{\text{DS}}=0\text{V}$	—	—	1	$\mu\text{A}$
	$\text{I}_{\text{GSSR}}$	$\text{V}_{\text{GS}}=-20\text{V}, \text{V}_{\text{DS}}=0\text{V}$	—	—	-1	$\mu\text{A}$
<b>On Characteristics</b>						
Gate-Source Threshold Voltage	$\text{V}_{\text{GS(th)}}$	$\text{V}_{\text{DS}}=\text{V}_{\text{GS}}, \text{I}_D=250\text{uA}$	2.0	—	4.0	V
Drain-Source On-State Resistance	$\text{R}_{\text{DS(on)}}$	$\text{V}_{\text{GS}}=10\text{V}, \text{I}_D=3.5\text{A}$	—	0.53	0.58	$\Omega$
<b>Dynamic Characteristics</b>						
Input Capacitance	$\text{C}_{\text{iss}}$	$\text{V}_{\text{DS}}=25\text{V}, \text{V}_{\text{GS}}=0\text{V},$ $f=1.0\text{MHZ}$	—	650	—	pF
Output Capacitance	$\text{C}_{\text{oss}}$		—	310	—	pF
Reverse Transfer Capacitance	$\text{C}_{\text{rss}}$		—	38	—	pF
<b>Switching Characteristics</b>						
Turn-On Delay Time	$t_{\text{d(on)}}$	$\text{V}_{\text{DD}}=400\text{V}, \text{I}_D=3\text{A},$ $\text{R}_G=6.8\Omega$ (Note3,4)	—	9	—	ns
Turn-On Rise Time	$t_r$		—	6.2	—	ns
Turn-Off Delay Time	$t_{\text{d(off)}}$		—	41	—	ns
Turn-Off Fall Time	$t_f$		—	30	—	ns
Total Gate Charge	$\text{Q}_g$	$\text{V}_{\text{DS}}=480\text{V}, \text{I}_D=7\text{A},$ $\text{V}_{\text{GS}}=10\text{V}$ , (Note3,4)	—	18	—	nC
Gate-Source Charge	$\text{Q}_{\text{gs}}$		—	8	—	nC
Gate-Drain Charge	$\text{Q}_{\text{gd}}$		—	2	—	nC
<b>Drain-Source Body Diode Characteristics and Maximum Ratings</b>						
Continuous Diode Forward Current	$\text{I}_S$		—	—	7	A
Pulsed Diode Forward Current	$\text{I}_{\text{SM}}$		—	—	24	A
Diode Forward Voltage	$\text{V}_{\text{SD}}$	$\text{I}_S=3.5\text{A}, \text{V}_{\text{GS}}=0\text{V}$	—	—	1.3	V
Reverse Recovery Time	$t_{\text{rr}}$	$\text{V}_{\text{GS}}=0\text{V}, \text{I}_S=3\text{A},$ $d\text{I}_F/dt=100\text{A/us}$ , (Note4)	—	257	—	ns
Reverse Recovery Charge	$\text{Q}_{\text{rr}}$		—	2.8	—	$\mu\text{C}$

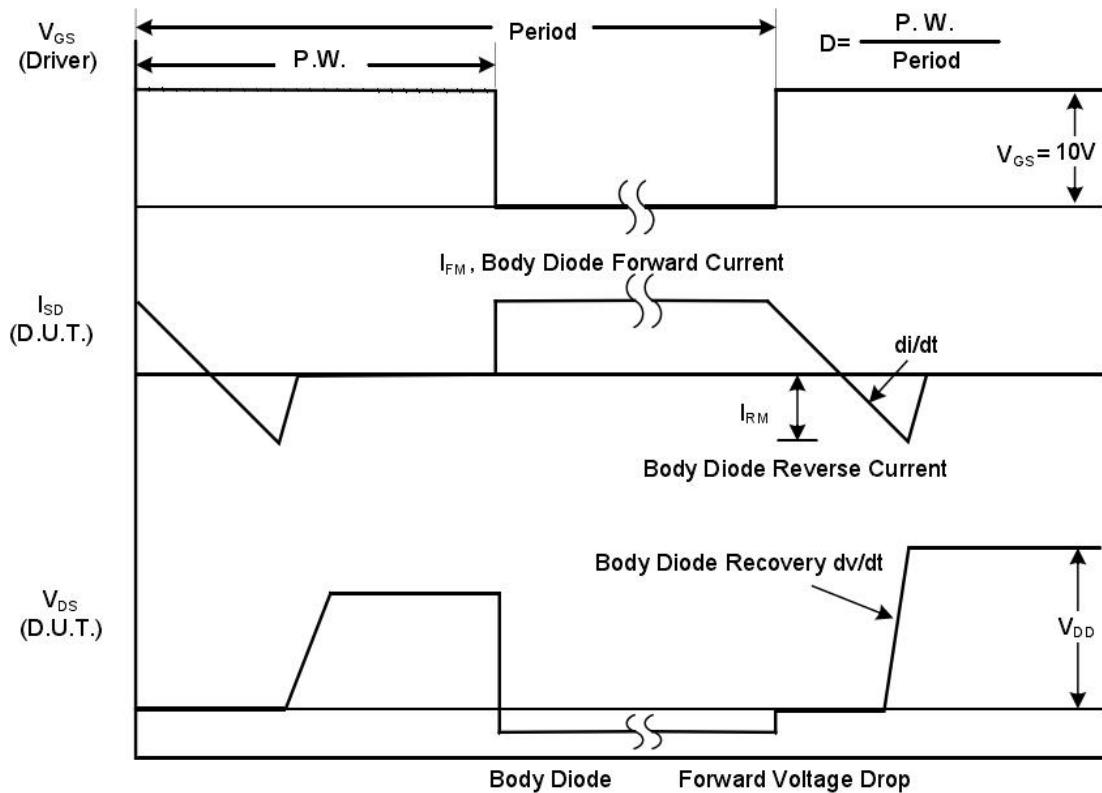
#### Notes

- Repetitive Rating:pulse width limited by maximum junction temperature.
- $\text{V}_{\text{DD}}=50\text{V}, L=10\text{mH}$ , starting  $T_J=25^\circ\text{C}$ .
- $I_{\text{SD}} \leq I_D, dI/dt=200\text{A/us}, V_{\text{DD}} \leq \text{BV}_{\text{DSS}}$ , starting  $T_J=25^\circ\text{C}$ , Pulse width $\leq 300\text{us}$ ; duty cycle $\leq 2\%$ .
- Repetitive rating; pulse width limited by maximum junction temperature.

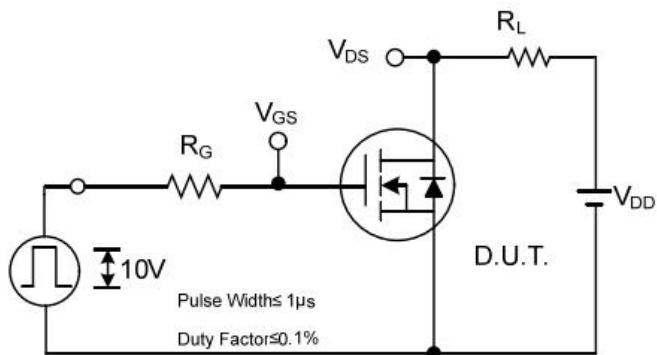
## RATING AND CHARACTERISTIC CURVES



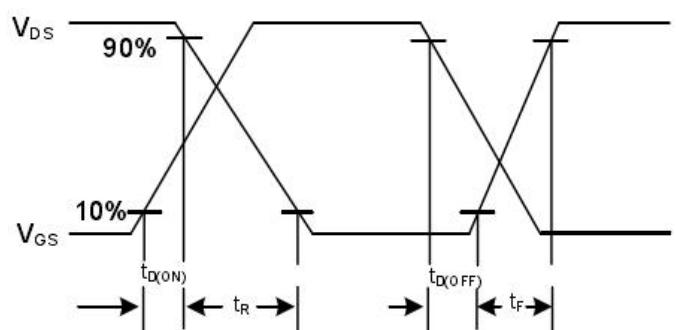
Peak Diode Recovery dv/dt Test Circuit



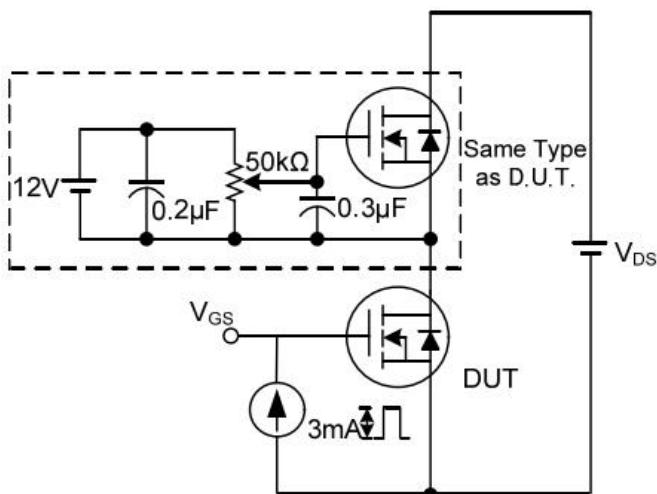
Peak Diode Recovery dv/dt Waveforms



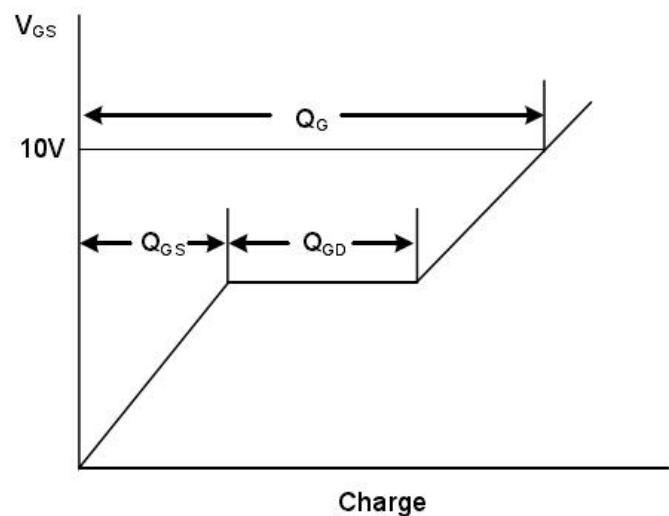
Switching Test Circuit



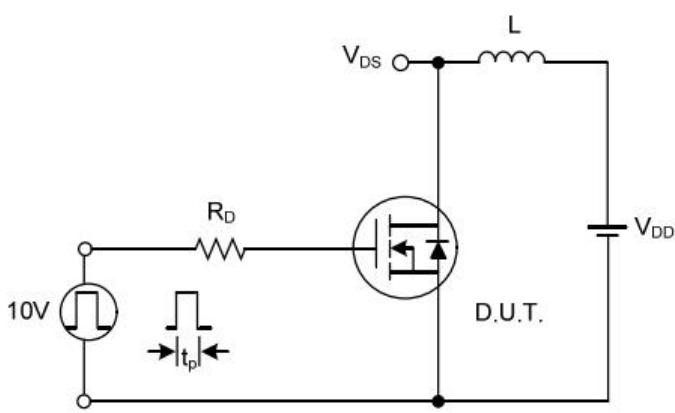
Switching Waveforms



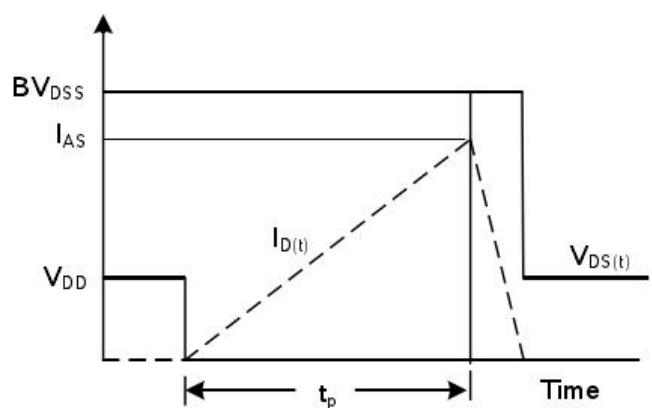
Gate Charge Test Circuit



Gate Charge Waveform

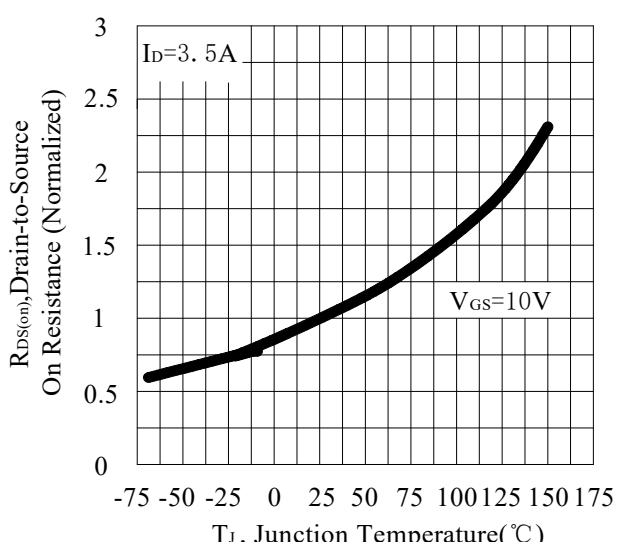
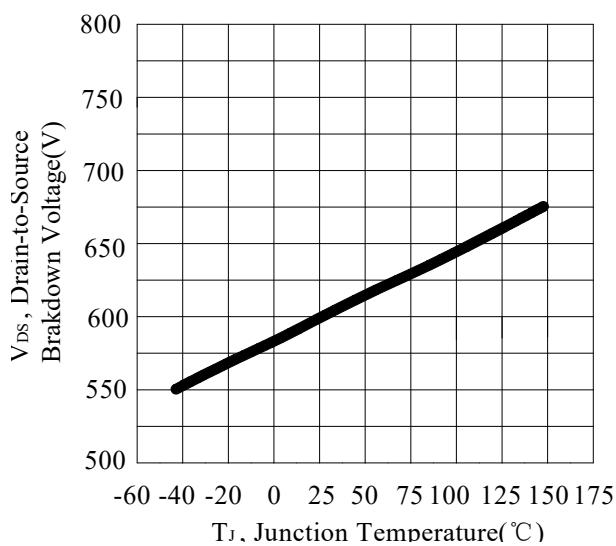
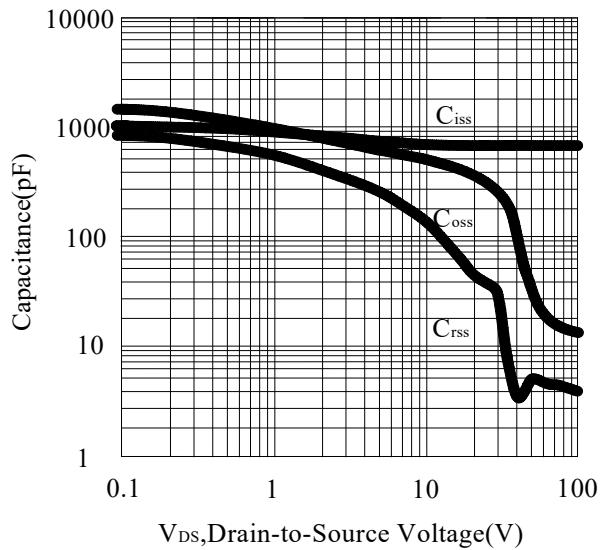
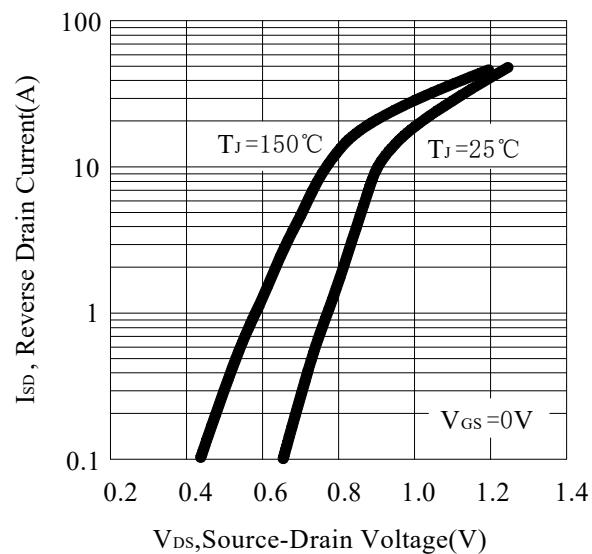
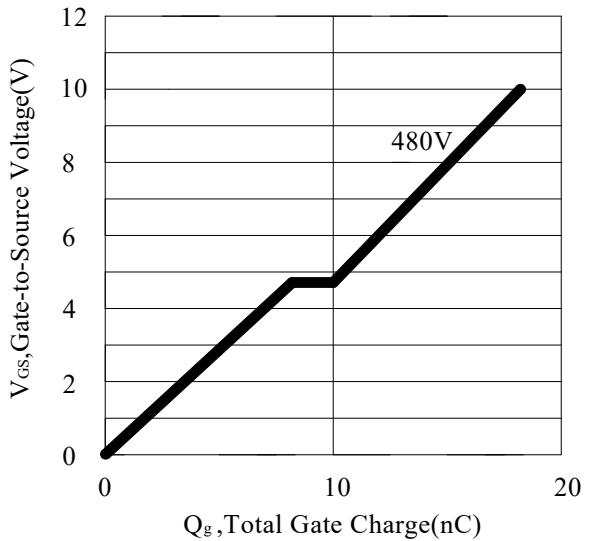
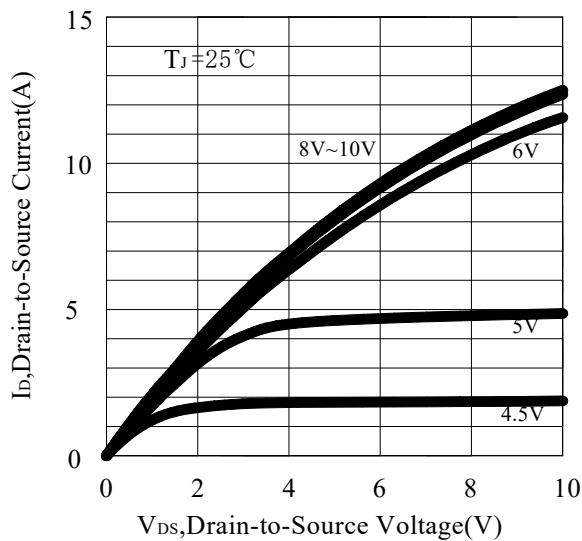


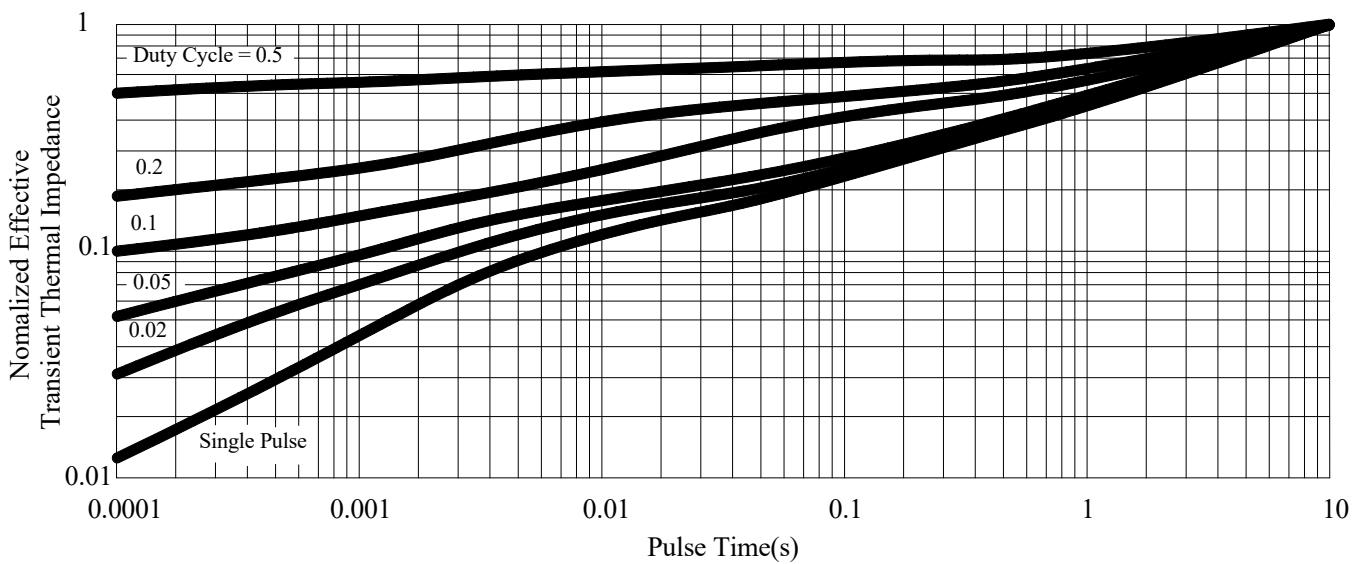
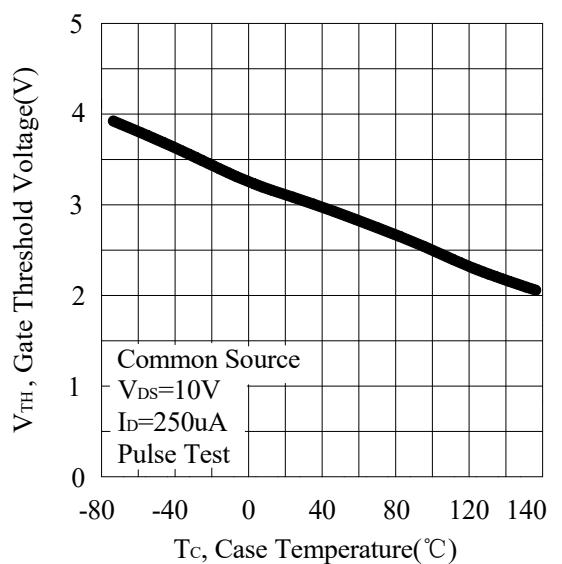
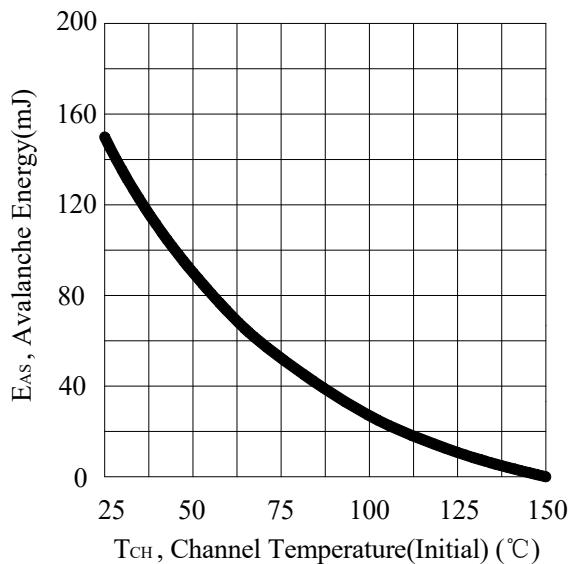
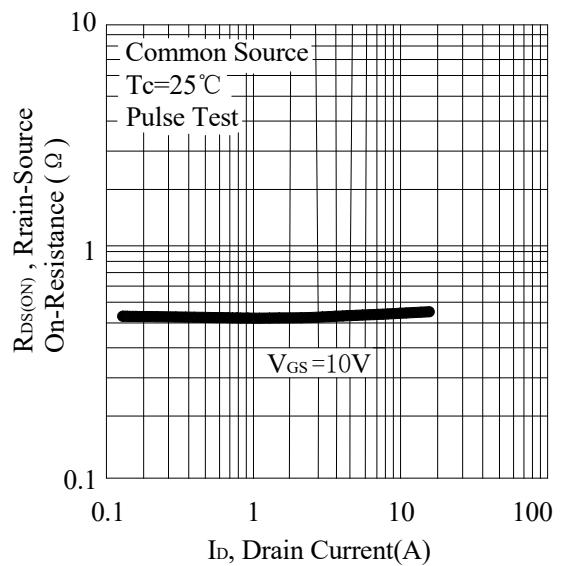
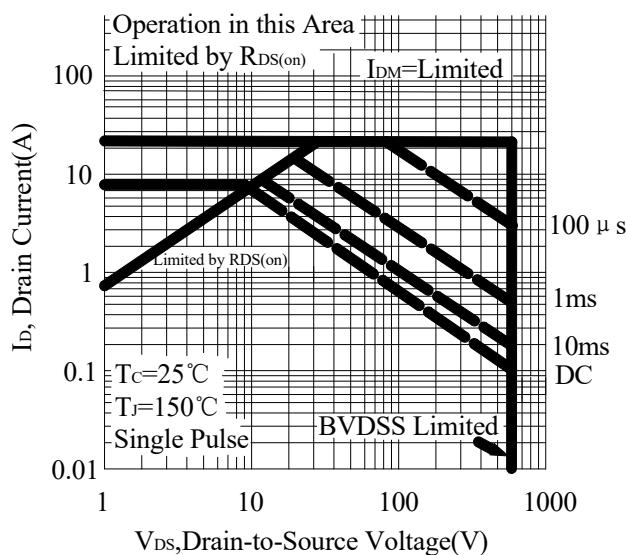
Unclamped Inductive Switching Test Circuit



Unclamped Inductive Switching Waveforms

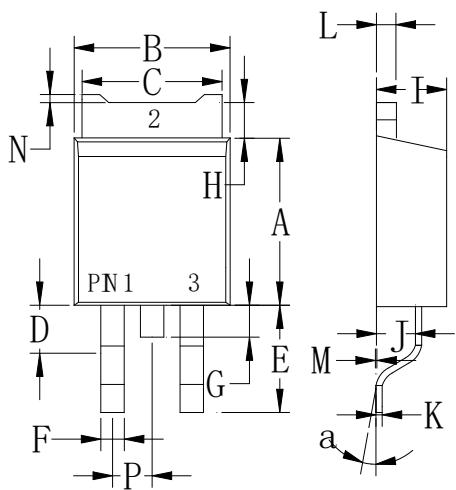
## RATING AND CHARACTERISTIC CURVES





## PACKAGE OUTLINE DIMENSIONS

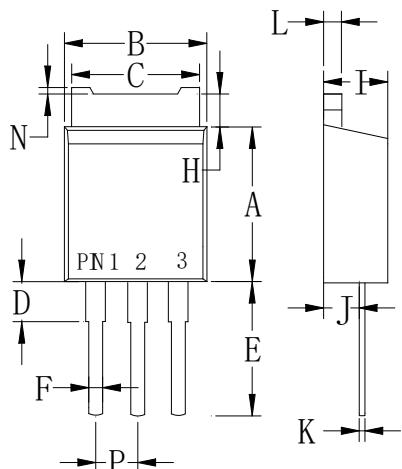
**TO-252**



TO-252		
Dim	Min	Max
A	.230 (5.85)	.246 (6.25)
B	.250 (6.35)	.264 (6.75)
C	.207 (5.27)	.218 (5.54)
D	.037 (0.93)	.045 (1.14)
E	.106 (2.70)	.138 (3.50)
F	.028 (0.72)	.033 (0.84)
G	.024 (0.60)	.041 (1.05)
H	.028 (0.72)	.043 (1.10)
I	.085 (2.15)	.096 (2.45)
J	.037 (0.95)	.047 (1.20)
K	.018 (0.45)	.026 (0.65)
L	.018 (0.45)	.024 (0.60)
P	.081 (2.05)	.094 (2.40)
M	.000 (0.00)	.006 (0.15)
N	--	.008 (0.20)
a	0°	10°

Dimensions in inches and (millimeters)

**TO-251**



TO-251		
Dim	Min	Max
A	.230 (5.85)	.246 (6.25)
B	.250 (6.35)	.266 (6.75)
C	.207 (5.27)	.218 (5.54)
D	.037 (0.93)	.045 (1.14)
E	.173 (4.40)	.205 (5.20)
F	.028 (0.72)	.033 (0.84)
H	.028 (0.70)	.043 (1.10)
I	.085 (2.15)	.096 (2.45)
J	.037 (0.95)	.047 (1.20)
K	.018 (0.45)	.026 (0.65)
L	.018 (0.45)	.024 (0.60)
N	--	.008 (0.20)
P	.081 (2.05)	.094 (2.40)

Dimensions in inches and (millimeters)

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